

SLLS667A-FEBRUARY 2006-REVISED MAY 2006

3.3 V FULL-DUPLEX RS-485/RS-422 DRIVERS AND BALANCED RECEIVERS

FEATURES

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- **Designed for INTERBUS Applications**
- **Balanced Receiver Thresholds**
- 1/2 Unit-Load (up to 64 nodes on the bus)
- **Bus-Pin ESD Protection 15 kV HBM**
- Bus-Fault Protection of -7V to 12V •
- **Thermal Shutdown Protection**
- Power-Up/Down Glitch-free Bus Inputs and . Outputs
- High Input Impedance with Low V_{CC} .
- Monotonic Outputs During Power Cycling
- **5V Tolerant Inputs**

APPLICATIONS

- **Digital Motor Control**
- **Utility Meters** •
- **Chassis-to-Chassis Interconnections**
- **Electronic Security Stations** .
- Industrial, Process, and Building Automation •
- Point-of-Sale (POS) Terminals and Networks
- **DTE/DCE** Interfaces

DESCRIPTION

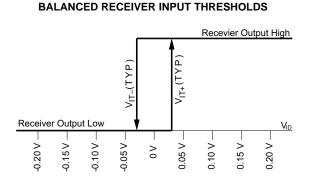
The SN65HVD379 is a differential line driver and differential-input line receiver that operates with a 3.3-V power supply. Each driver and receiver has separate input and output pins for full-duplex bus communication designs. They are designed for balanced transmission lines and interoperation with ANSI TIA/EIA-485A, TIA/EIA-422-B, ITU-T v.11, and ISO 8482:1993 standard-compliant devices.

These differential bus drivers and receivers are monolithic, integrated circuits designed for full-duplex bi-directional data communication on multipoint bus-transmission lines at signaling rates⁽¹⁾ up to 25 Mbps. The SN65HVD379 is fully enabled with no external enabling pins.

The 1/2 unit load receiver has a higher receiver input resistance. This results in lower bus leakage currents over the common-mode voltage range, and reduces the total amount of current that an RS-485 driver is forced to source or sink when transmitting.

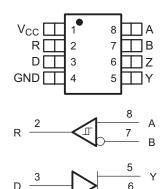
The balanced differential receiver input threshold makes the SN65HVD379 more compatible with fieldbus requirements that define an external failsafe structure.

The signaling rate of a line is the number of voltage (1) transitions that are made per second expressed in the units bps (bits per second).



SN65HVD379

D PACKAGE (TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

A

SN65HVD379



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION

SIGNALING RATE	UNIT LOADS	PART NUMBER ⁽¹⁾	SOIC MARKING
25 Mbps	1/2	SN65HVD379	

(1) These are The D package is available taped and reeled. Add an R suffix to the part number (ie. SN65HVD379DR).

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾⁽²⁾

		UNIT
V _{CC}	Supply voltage range	–0.3 V to 6 V
V_A, V_B, V_Y, V_Z	Voltage range at any bus terminal (A, B, Y, Z)	–9 V to 14 V
V _{TRANS}	Voltage input, transient pulse through 100 Ω . See Figure 8 (A, B, Y, Z) ⁽³⁾	-50 to 50 V
VI	Input voltage range (D, DE, RE)	-0.5 V to 7 V
P _{CONT}	Continuous total power dissipation	Internally limited ⁽⁴⁾
0	Output current (receiver output only, R)	11 mA

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) This tests survivability only and the output state of the receiver is not specified.

(4) The Thermal shutdown protection circuit internally limits the continuous total power dissipation. Thermal shutdown typically occurs when the junction temperature reaches 165°C.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range unless otherwise noted

PARAME	TER	MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage	Supply voltage				V
$\rm V_{I}~\rm or~V_{IC}$	Voltage at any bus termina	(separately or common mode)	-7 ⁽¹⁾		12	v
1/t _{UI}	Signaling rate	SN65HVD379			25	Mbps
RL	Differential load resistance		54	60		Ω
V _{IH}	High-level input voltage	D	2		V_{CC}	
V _{IL}	Low-level input voltage	D	0		0.8	V
V _{ID}	Differential input voltage		-12		12	
	Lligh lovel output ourrest	Driver	-60			mA
ЮН	High-level output current	Receiver	-8			ША
		Driver			60	~ ^
I _{OL}	Low-level output current	Receiver			8	mA
T _A	Ambient still-air temperatur	e	-40		85	°C

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

ELECTROSTATIC DISCHARGE PROTECTION

PARAMETER TEST CONDITIONS		MIN TYP ⁽¹⁾ MAX	UNIT
Human body model	Bus terminals and GND	±16	
Human body model ⁽²⁾	All pins	±4	kV
Charged-device-model ⁽³⁾	All pins	±1	

(1) All typical values at 25°C with 3.3-V supply.

(2) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(3) Tested in accordance with JEDEC Standard 22, Test Method C101.

DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMET	ER	TEST COND	TEST CONDITIONS			MAX	UNIT
V _{I(K)}	Input clamp voltage		I _I = -18 mA	-1.5				
			I _O = 0		2.0		V _{CC}	
	Standy atota different	ial autaut valtaga	$R_L = 54 \Omega$, See Figure	1 ⁽²⁾ (RS-485)	1.5	2.0		
V _{OD(SS)}	Steady-state different	iai ouiput voltage	$R_L = 100 \Omega$, See Figur	<mark>e 1</mark> (RS-422)	2.0	2.3		
			$V_{\text{test}} = -7 \text{ V}$ to 12 V, Se	ee Figure 2	1.5			
$\Delta V_{OD(SS)} $	Change in magnitude differential output volt		$R_L = 54 \Omega$, See Figure	$R_L = 54 \Omega$, See Figure 1 and Figure 2			0.2	V
V _{OD(RING)}	Differential Output Vo undershoot	ltage overshoot and	$R_L = 54 \Omega, C_L = 50 pF$ (Figure 3 for definitions			10% ⁽³⁾		
V _{OC(PP)}	Peak-to-peak commo	n-mode output voltage				0.5		
V _{OC(SS)}	Steady-state common-mode output voltage		See Figure 3	1.6		2.3		
$\Delta V_{OC(SS)}$	Change in steady-sta voltage	te common-mode output		-0.05		0.05		
$I_{Z(Z)}$ or			$V_{CC} = 0 V$, V_Z or $V_Y = 12 V$, Other input at 0 V				90	A
$I_{Y(Z)}$	High-impedance state	e output current	$V_{CC} = 0 V, V_Z \text{ or } V_Y = 0$ Other input at 0 V	–7 V,	-10			μA
Z(S) ^{Or} Short Circuit output Current		V_Z or $V_Y = -7 V$	Other input	-250		250	A	
I _{Y(S)}	Short Circuit output C	urrent	$V_Z \text{ or } V_Y = 12 \text{ V}$ at 0 V		-250		250	mA
l _l	Input current	D	$V_{I} = 0 \text{ or } V_{I} = 2.0$		0		100	μA
C _(OD)	Differential output cap	pacitance	V _{OD} = 0.4 sin (4E6πt) - V _{CC} at 0 V	+ 0.5 V,		16		pF

(1) All typical values are at 25° C and with a 3.3-V supply.

(2) V_{CC} is 3.3 Vdc ± 5%

(3) 10% of the peak-to-peak Differential Output voltage swing, per TIA/EIA-485.

DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output		4	10	18	20
t _{PHL}	Propagation delay time, high-to-low-level output		4	10	10	ns
t _r	Differential output signal rise time	$R_L = 54 \Omega$, $C_L = 50 pF$, See Figure 5	2.5	F	12	20
t _f	Differential output signal fall time		2.5	5	12	ns
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH})			0.6		ns
t _{sk(pp)} ⁽²⁾	Part-to-part skew			1		ns

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIC	TEST CONDITIONS			MAX	UNIT
V _{IT+}	Positive-going differential input threshold voltage	$I_0 = -8 \text{ mA}$	$I_0 = -8 \text{ mA}$			0.2	V
V _{IT-}	Negative-going differential input threshold voltage	I _O = 8 mA	I _O = 8 mA				v
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})						mV
V	Output voltage	$V_{ID} = 200 \text{ mV}, I_O = -8 \text{ mA}, S$	2.4			V	
Vo	Output voltage	$V_{ID} = -200 \text{ mV}, I_O = 8 \text{ mA}, S$	ee Figure 7			0.4	v
	Bus input current	$V_A \text{ or } V_B = 12 \text{ V}$			0.20	0.35	
I _A or		$V_A \text{ or } V_B = 12 \text{ V}, V_{CC} = 0 \text{ V}$	Other input		0.24	0.40	A
Ι _B		$V_A \text{ or } V_B = -7 \text{ V}$	at 0 V	-0.35	-0.18		mA
		V_A or V_B = -7 V, V_{CC} = 0 V		-0.25	-0.13		
C _{ID}	Differential input capacitance	V _{ID} = 0.4 sin (4E6πt) + 0.5 V	V _{ID} = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V		15		pF
I _{CC}	Supply current	D at 0 V or V _{CC} and No Load	1			2.1	mA

(1) All typical values are at 25°C and with a 3.3-V supply.

RECEIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output	$V_{ID} = -1.5 \text{ V}$ to 1.5 V, $C_{L} = 15 \text{ pF}$,		26	45	20
t _{PHL}	Propagation delay time, high-to-low-level output	See Figure 7		20	40	ns
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH})				7	
t _{sk(pp)}	Part-to-part skew ⁽²⁾			5		
t _r	Output signal rise time				5	
t _f	Output signal fall time				6	

All typical values are at 25°C and with a 3.3-V supply
t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

DEVICE POWER DISSIPATION – PD

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
P	Device power dissipation	R_L = 60 , C_L = 50 pF, Input to D a 50% duty cycle square wave at indicated signaling rate T_A = 85°C		197	mW

FUNCTION TABLES

	DRIVER		RECEIVER				
INPUT	OUTPUTS		DIFFERENTIAL INPUTS	OUTPUTS			
D	Y Z		$V_{ID} = V_A - V_B$	R			
Н	H L		V _{ID} ≤− 0.2 V	L			
L	L	Н	$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$?			
Open	L	Н	$0.2 \text{ V} \leq \text{V}_{\text{ID}}$	Н			

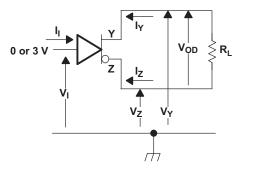
 V_{Y}

 V_{Z}

 $\Delta V_{OC(SS)}$

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PARAMETER MEASUREMENT INFORMATION



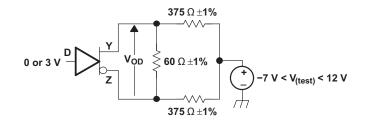


Figure 1. Driver V_{OD} Test Circuit and Voltage and Current Definitions



V_{OC(PP)}

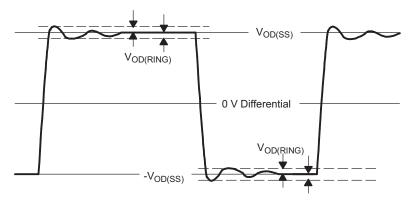
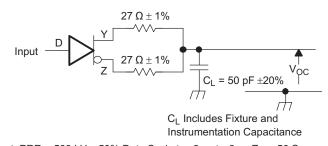


Figure 3. V_{OD(RING)} Waveform and Definitions

 $V_{\text{OD}(\text{RING})}$ is measured at four points on the output waveform, corresponding to overshoot and undershoot from the $V_{\text{OD}(\text{H})}$ and $V_{\text{OD}(\text{L})}$ steady state values.

7



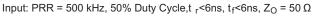


Figure 4. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



- 3 V

0 V

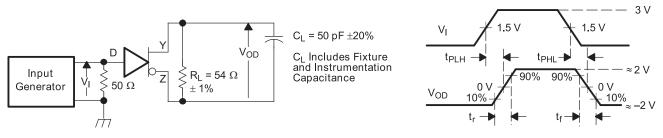
VOH

10% V_{OL}

1.5 V

1.5 V

PARAMETER MEASUREMENT INFORMATION (continued)



Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z_o = 50 Ω

Figure 5. Driver Switching Test Circuit and Voltage Waveforms

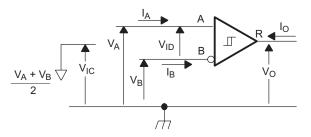
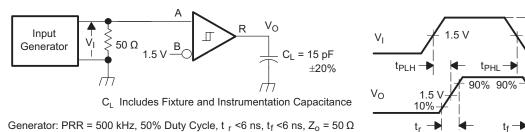


Figure 6. Receiver Voltage and Current Definitions



Generator: PRR = 500 kHz, 50% Duty Cycle, t $_{\rm r}$ <6 ns, t $_{\rm f}$ <6 ns, Z $_{\rm o}$ = 50 Ω t_r -

Figure 7. Receiver Switching Test Circuit and Voltage Waveforms

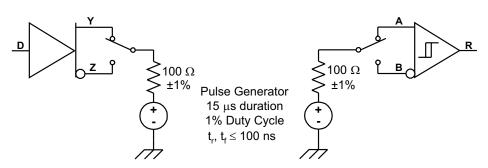
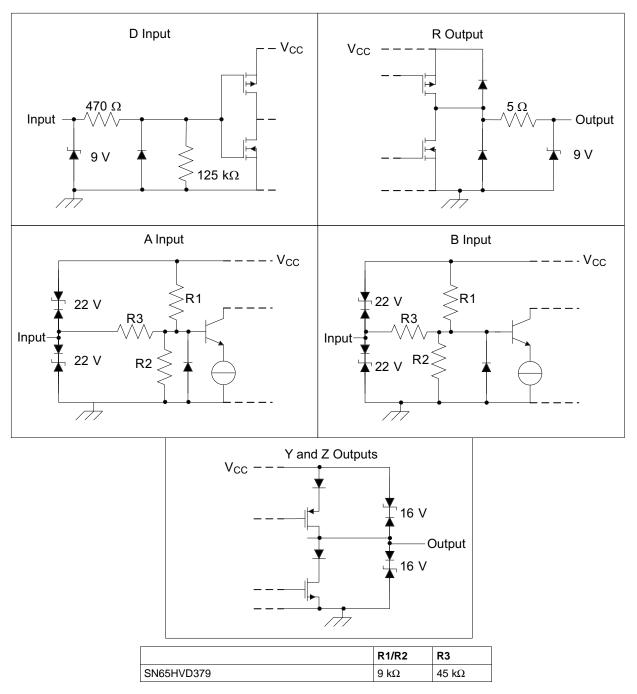


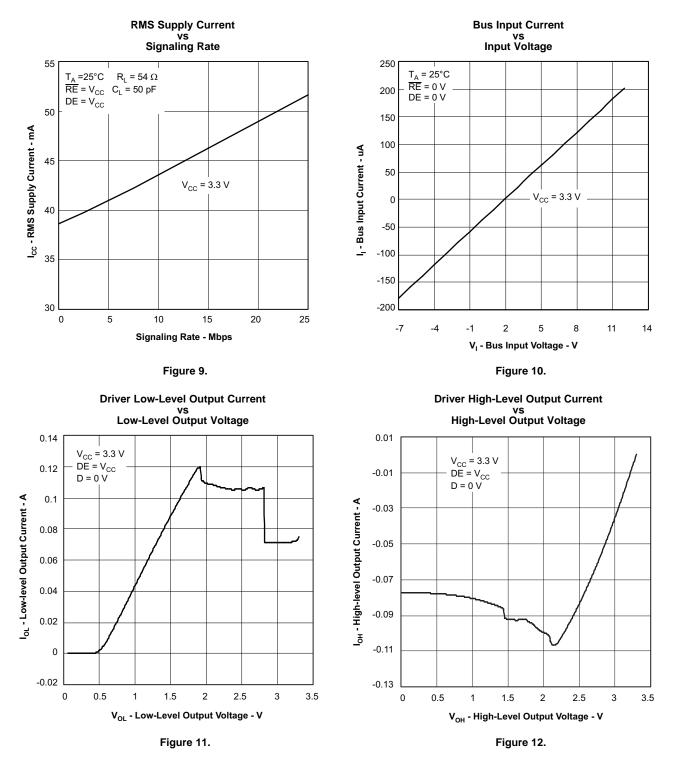
Figure 8. Test Circuit, Transient Over Voltage Test

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EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS

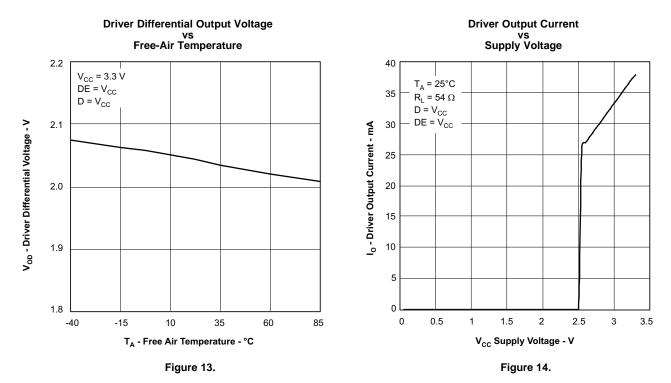
TYPICAL CHARACTERISTICS





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TYPICAL CHARACTERISTICS (continued)



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN65HVD379D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD379DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD379DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD379DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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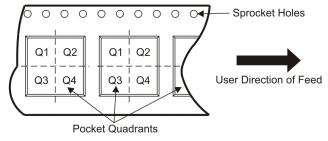
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*Al	I dimensions are nominal	

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD379DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD379DR	SOIC	D	8	2500	346.0	346.0	29.0

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AA.



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